

One Watt High Voltage Transistor

PNP Silicon

• This device is available in Pb-free package(s). Specifications herein apply to both standard and Pb-free devices. Please see our website at www.onsemi.com for specific Pb-free orderable part numbers, or contact your local ON Semiconductor sales office or representative.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V _{CEO}	-300	Vdc
Collector - Base Voltage	V _{CBO}	-300	Vdc
Emitter - Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current — Continuous	I _C	-500	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	1.0 8.0	Watt mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	2.5 20	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	125	°C/W
Thermal Resistance, Junction to Case	$R_{ heta JC}$	50	°C/W

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

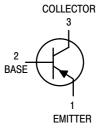
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage ⁽¹⁾ $ (I_C = -1.0 \text{ mAdc}, I_B = 0) $	V _{(BR)CEO}	-300	_	Vdc
Collector–Base Breakdown Voltage ($I_C = -100 \mu Adc$, $I_E = 0$)	V _{(BR)CBO}	-300	_	Vdc
Emitter–Base Breakdown Voltage $(I_E = -100 \ \mu Adc, \ I_C = 0)$	V _{(BR)EBO}	-5.0	_	Vdc
Collector Cutoff Current (V _{CB} = -200 Vdc, I _E = 0)	I _{CBO}	_	-0.25	μAdc
Emitter Cutoff Current (V _{EB} = -3.0 Vdc, I _C = 0)	I _{EBO}	=	-0.1	μAdc

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

MPSW92

ON Semiconductor Preferred Device





Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

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Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS ⁽¹⁾	•			
DC Current Gain $ \begin{aligned} &(I_C = -1.0 \text{ mAdc, } V_{CE} = -10 \text{ Vdc)} \\ &(I_C = -10 \text{ mAdc, } V_{CE} = -10 \text{ Vdc)} \\ &(I_C = -30 \text{ mAdc, } V_{CE} = -10 \text{ Vdc)} \end{aligned} $	h _{FE}	25 40 25	_ _ _	_
Collector–Emitter Saturation Voltage (I _C = -20 mAdc, I _B = -2.0 mAdc)	V _{CE(sat)}	_	-0.5	Vdc
Base-Emitter Saturation Voltage (I _C = -20 mAdc, I _B = -2.0 mAdc)	V _{BE(sat)}	_	-0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS	•	•	•	•
Current-Gain — Bandwidth Product (I _C = -10 mAdc, V _{CE} = -20 Vdc, f = 20 MHz)	f _T	50	_	MHz
Collector-Base Capacitance (V _{CB} = -20 Vdc, I _E = 0, f = 1.0 MHz)	C _{cb}	_	6.0	pF

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

MPSW92

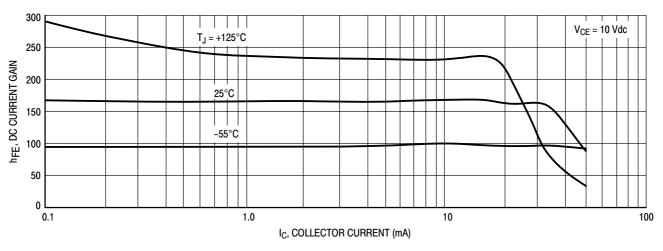


Figure 1. DC Current Gain

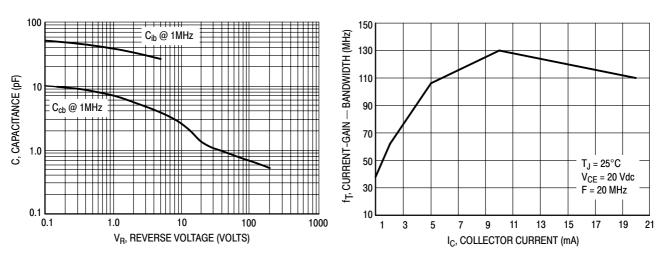
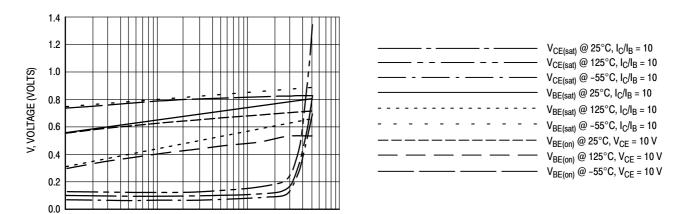


Figure 2. Capacitance



100

Figure 3. Current-Gain — Bandwidth

I_C, COLLECTOR CURRENT (mA)

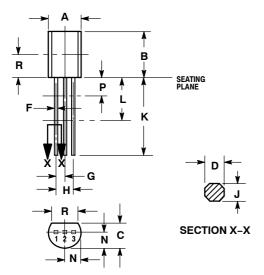
Figure 4. "ON" Voltages

0.1

MPSW92

PACKAGE DIMENSIONS

TO-92 (TO-226) **CASE 29-10** ISSUF AL



YLE 1:

PIN 1. EMITTER BASE

COLLECTOR

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.

 4. DIMENSION F APPLIES BETWEEN P AND L.
- DIMENSIONS D AND J APPLY BETWEEN L AND K MIMIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.44	5.21	
В	0.290	0.310	7.37	7.87	
С	0.125	0.165	3.18	4.19	
D	0.018	0.021	0.457	0.533	
F	0.016	0.019	0.407	0.482	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.018	0.024	0.46	0.61	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.135		3.43		

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